NSN 5961-00-230-8855

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-230-8855 **Inclosure Material:** Metal **Overall Length:** 0.340 inches **Overall Diameter:** 0.500 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 120.0 collector to base voltage/static/emitter open and 75.0 collector to emitter voltage/static/base open and 90.0 collector to emitter reverse voltage and 7.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 5.00 amperes source cutoff current and 10.00 amperes source cutoff current **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius case **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No